



#### 100V N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI<sup>®</sup>

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
	80mΩ @ V <sub>GS</sub> = 10V	4.2A
100V	99mΩ @ V <sub>GS</sub> = 6.0V	3.6A

## Description

This MOSFET has been designed to minimize the on-state resistance  $(R_{DS(on)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

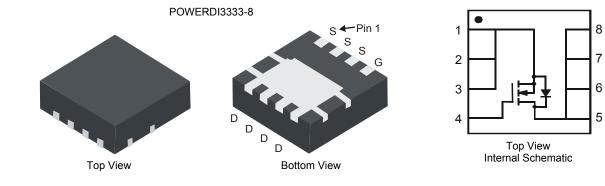
- Power Management Functions
- DC-DC Converters

## Features and Benefits

- Low R<sub>DS(ON)</sub> ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: POWERDI3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram Terminals: Finish — Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.034 grams (approximate)



### Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
DMN10H099SFG-7	Standard	POWERDI3333-8	2000/Tape & Reel
DMN10H099SFG-13	Standard	POWERDI3333-8	3000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

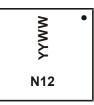
2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

# **Marking Information**

Notes:



N12 = Product Type Marking Code YYWW = Date Code Marking YY = Last digit of year (ex: 13 = 2013) WW = Week code (01 ~ 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	<b>Value</b> 100	Units V		
Drain-Source Voltage	V <sub>DSS</sub>				
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	4.2 3.3	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	t<10s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	5.8 4.5	А
	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	3.6 2.9	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = 6V	t<10s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	5.2 4.1	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I <sub>DM</sub>	20	А

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Dower Dissinction (Note 5)	T <sub>A</sub> = +25°C	D	0.98	W
Total Power Dissipation (Note 5)	T <sub>A</sub> = +70°C	PD	0.57	
Thermal Desistance, Junction to Ambient (Note 5)	Steady state	P	131	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	$R_{ heta JA}$	76	
Tatal Dawar Dissinction (Nata 6)	T <sub>A</sub> = +25°C	D	2.31	w
Total Power Dissipation (Note 6)	T <sub>A</sub> = +70°C	PD	1.18	
Thermal Desistance Junction to Ambient (Note 6)	Steady state	P	55	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	28	
Thermal Resistance, Junction to Case (Note 6)	R <sub>0JC</sub>	6.9		
Operating and Storage Temperature Range		T <sub>J.</sub> T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	-	-	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	-	-	1.0	μA	V <sub>DS</sub> = 80V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	Igss	-	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	1.5	2.0	3.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	<b>D</b>	-	54	80	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 3.3A	
	R <sub>DS (ON)</sub>	-	58	99		V <sub>GS</sub> = 6.0V, I <sub>D</sub> = 3.0A	
Forward Transfer Admittance	Y <sub>fs</sub>	-	13	-	S	V <sub>DS</sub> = 10V, I <sub>D</sub> = 3.3A	
Diode Forward Voltage	V <sub>SD</sub>	-	0.77	-	V	$V_{GS} = 0V, I_{S} = 3.2A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	-	1172	-	pF	N/ 50X/X/ 0X/	
Output Capacitance	Coss	-	40.8	-	pF	V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	-	31.3	-	pF		
Gate Resistance	Rg	-	1.6	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge V <sub>GS</sub> = 10V	Qg	-	25.2	-	nC		
Total Gate Charge V <sub>GS</sub> = 4.5V	Qg	-	12.2	-	nC	1/2 = 50/2 + 220	
Gate-Source Charge	Q <sub>gs</sub>	-	5.3	-	nC	V <sub>DS</sub> = 50V, I <sub>D</sub> = 3.3A	
Gate-Drain Charge	Q <sub>gd</sub>	-	5.9	-	nC		
Turn-On Delay Time	t <sub>D(on)</sub>	-	5.4	-	ns		
Turn-On Rise Time	tr	-	5.9	-	ns	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 50V,	
Turn-Off Delay Time	t <sub>D(off)</sub>	-	20.0	-	ns	R <sub>G</sub> = 6.0Ω, I <sub>D</sub> = 3.3A	
Turn-Off Fall Time	t <sub>f</sub>	-	7.3	-	ns	]	

Notes:

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

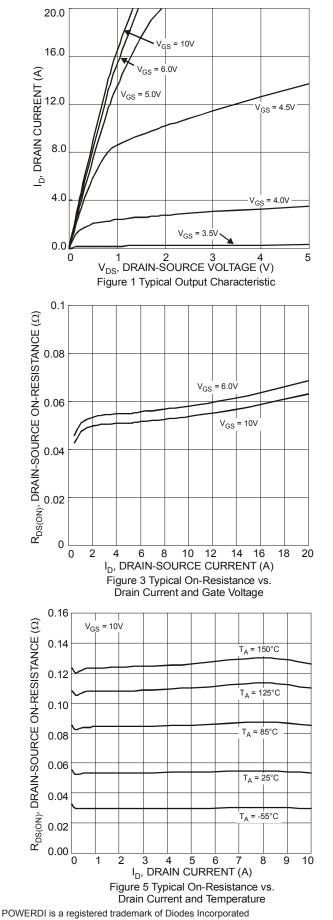
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

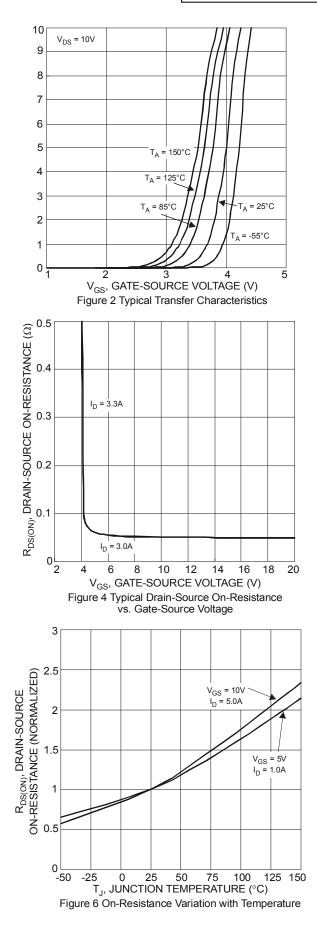
7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing

## DMN10H099SFG

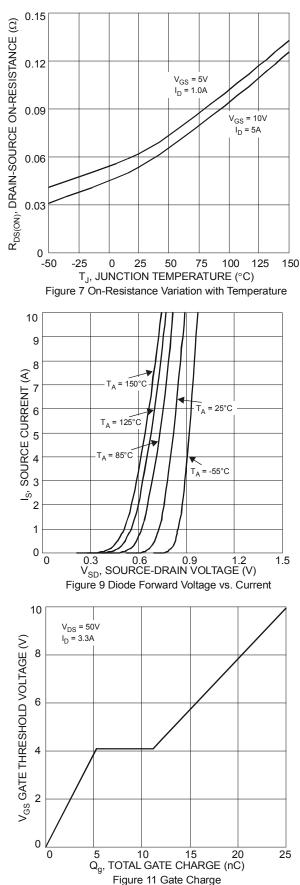






DMN10H1099SFG Document number: DS36371 Rev. 2 - 2





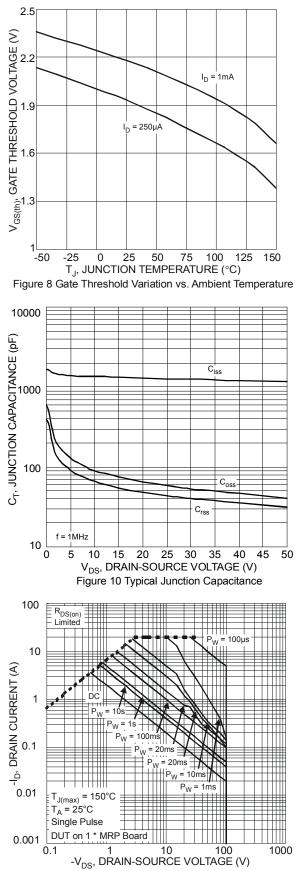
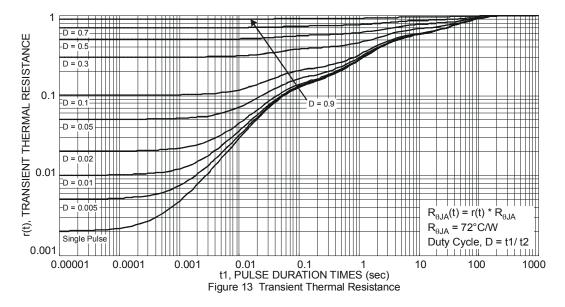


Figure 12 SOA, Safe Operation Area

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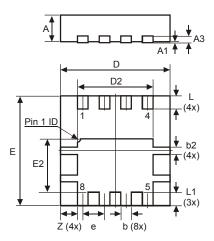
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# **Package Outline Dimensions**

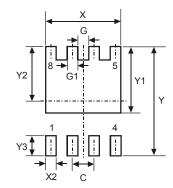
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI3333-8					
Dim	Min Max		Тур		
D	3.25	3.35	3.30		
Е	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E2	1.56	1.66	1.61		
Α	0.75	0.85	0.80		
A1	0	0.05	0.02		
A3	-	-	0.203		
b	0.27	0.37	0.32		
b2			0.20		
L	0.35	0.45	0.40		
L1	-	-	0.39		
е	-	-	0.65		
Ζ	_	_	0.515		
All Dimensions in mm					

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.650
G	0.230
G1	0.420
Y	3.700
Y1	2.250
Y2	1.850
Y3	0.700
X	2.370
X2	0.420

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